



TWO-WIRE AUTOMOTIVE HALL SWITCHES INTEGRATED SELF-DIAGNOSTICS

Description

The DIODES[™] AH3241Q-AH3244Q/AH3280Q-AH3282Q are high voltage, high sensitivity, two-wire Hall Effect Unipolar/Latch switch ICs with integrated self-diagnostics and automotive-compliant AEC-Q100 qualification; designed for position and proximity sensing in automotive applications, such as seat and seatbelt buckle, transmission actuator, gear position, wiper, door/trunk closure, etc.

To support a wide range of demanding applications, the AH3241Q-AH3244Q/AH3280Q-AH3282Q are optimized to operate over a supply range of 2.7V to 27V. These features include a chopperstabilized architecture and an internal bandgap regulator to provide temperature compensated supply for internal circuits. For robustness and protection, the device has built-in reverse blocking diode with a Zener clamp on the supply.

The built-in thermal protection also shuts down the chip if temperature rises to an abnormal value. This will automatically restart the chip once the junction temperature drops below the safe value.

For AH3241Q, AH3242Q, AH3243Q, and AH3244Q 2-wire unipolar switches: when the flux density (south pole) exceeds B_{OP} , the supply current state is turned on (low or high). The output is held until a magnetic flux density falls below B_{RP} , causing output current to be turned off.

For AH3280Q, AH3281Q, and AH3282Q 2-wire latch switches: when the magnetic flux density is larger than B_{OP} , output current is turned on (high). The output state is held until a magnetic flux density reversal falls below B_{RP} , causing output current to be turned off (low).

Features and Performance

- Unipolar: AH3241Q, AH3242Q, AH3243Q, AH3244Q
- Latch: AH3280Q, AH3281Q, AH3282Q
- Output Polarity:
 - Direct: AH3242Q, AH3243Q
 - Inverted: AH3241Q, AH3244Q
- Wide Supply Voltage Operation: 2.7V to 27V
 - Temperature Coefficient -1100ppm/°C
- (AH3242Q, AH3243Q, AH3244Q)
- Chopper Stabilized Design Provides:
 - Superior Temperature Stability
 - Minimal Switch Point Drift
 - Enhanced Immunity to Stress
- Battery polarity reverse connection protection
- Transient Spike Voltage Protection
- Overtemperature Shut Down and Auto-Restart
- UVLO Protection
- High ESD Rating: HBM = 8kV, CDM = 1kV
- Ready for ISO 26262
- Temperature Range: -40°C to +150°C
- Totally Lead-Free & Fully RoHS Compliant (Notes 1, 2)
 - Halogen and Antimony Free. "Green" Device (Note 3)

 The AH3241Q-AH3244Q/AH3280Q-AH3282Q

 are suitable for automotive applications requiring specific change control; these parts are AEC-Q100 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities. https://www.diodes.com/quality/product-definitions/

Notes:

- No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
 See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and
 - Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and<1000ppm antimony compounds.

Pin Assignments





Applications

- Position and proximity sensing in automotive applications
- Seat positioning
- Seatbelt buckles
- Wiper positioning
- Window lifters
- Gear selection positioning



Typical Applications Circuit



4. A 100nF or larger decoupling capacitor (CIN) between VDD and GND pins is needed for power stabilization and to strengthen noise immunity; CIN needs to be as close to IC as possible. Typical RL value is 100Ω. Larger or additional series resistor is recommended if there are disturbances on Note: VDD.

GND

 R_{L}

(2) Low-side sensing

ξ 100Ω VSENSE

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Pin Descriptions

Package: SC59 and SIP-3 (Ammo Pack and Bulk Pack)

| Pin Number | Pin Name | Function | |
|------------|-----------------|--|--|
| 1 | V _{DD} | ipply voltage input | |
| 2 | NC | No connection; can be connected to V_{DD} , GND, or left open. | |
| 3 | GND | Ground | |



Functional Block Diagram



Absolute Maximum Ratings (Note 5) (@ T_A = +25°C, unless otherwise specified.)

| Symbol | Parameter | Rating | Unit | | |
|---------------------------|------------------------------|-----------|-------|--|--|
| V _{DD} (Note 6) | Supply Voltage | 32 | V | | |
| V _{DDR} (Note 6) | Reverse supply voltage | -32 | V | | |
| В | Magnetic flux density | Unlimited | Gauss | | |
| T _{J_MAX} | Maximum junction temperature | 180 | °C | | |
| Ts | Storage Temperature | -55~180 | ٥° | | |
| ESD (HBM) | ESD (Human Body Model) | 8000 | V | | |
| ESD (CDM) | ESD (Charged Device Model) | 1000 | V | | |

Notes: 5. Stresses greater than the "Absolute Maximum Ratings" specified above may cause permanent damage to the device. These are stress ratings only; functional operation of the device at these or any other conditions exceeding those indicated in this specification is not implied. Device reliability may be affected by exposure to absolute maximum rating conditions for extended periods of time.

6. Should not be exceeded the maximum junction temperature and maximum duration of 500ms.

Recommended Operating Conditions (@ T_A = -40°C to +150°C, T_J = -40°C to +165°C unless otherwise specified.)

| - | | | | |
|-----------------|---|-----|-----|------|
| Symbol | Parameter | Min | Max | Unit |
| V _{DD} | Supply Voltage, between V_{DD} and GND pins | 2.7 | 27 | V |
| T _{OP} | Operating Ambient Temperature | -40 | 150 | °C |



| Symbol | Parameter | Conditions | Min | Тур | Max | Units |
|----------------------|--------------------------------------|--|------|------|-----|-------|
| V_{DD} | Supply voltage (Note 8) | - | 2.7 | 12 | 27 | V |
| I _{OFF} (2) | Supply current off state | V _{DD} = 2.7 to 27 V (AH3280Q, AH3282Q) | 2 | 3.3 | 5 | mA |
| I _{OFF} (1) | Supply current off state | V _{DD} = 2.7 to 27 V (AH3241Q, AH3242Q, AH3243Q, AH3244Q, AH3281Q) | 5 | 6 | 6.9 | mA |
| I _{ON} | Supply current on state | V _{DD} = 2.7 to 27 V | 12 | 14.5 | 17 | mA |
| Vuvlo | Undervoltage lockout threshold | Voltage dropping | - | 2.2 | 2.7 | V |
| t _{UVLO} | Undervoltage lockout reaction time | - | - | 10 | - | μs |
| I _{DDR} | Reverse supply current | $V_{DD} = -18V, T = -40^{\circ}C \text{ to } +150^{\circ}C$ | -1.5 | - | - | mA |
| T _{TP} | Thermal protection threshold | Junction temperature | - | 190 | - | °C |
| T _{TPR} | Thermal protection release threshold | Junction temperature | - | 180 | - | °C |
| FM | Maximum magnet switching frequency | $B > 3^*B_{OP}$, alternative square magnet field | 30 | 50 | - | kHz |
| Fc | Chopping frequency | - | - | 1000 | - | kHz |
| ISAFE | Safe mode supply current | Safe mode supply current / Error Current (mA) | 0.5 | 1 | 1.5 | mA |
| T _{PON} | Power on delay time (Note 9) | B > Bop+10GS | - | 28 | 40 | μs |
| TD | Response delay time (Note 10) | B > 3*B _{OP} | - | 7 | - | μs |
| T _{RF} | Current rise/fall time | V_{DD} = 12V, No bypass capacitor, C_{LOAD} = 50pF to GND | 0.1 | 0.3 | 1 | μs |
| POS | Power-Up state (Notes 9, 11) | t > T _{PON} (max), V _{DD} slew rate > 1V/µs | - | IOFF | - | - |
| - | Output jitter | B≥3*B _{OPMAX} 1000 successive square wave switching under 1KHz | - | ±3.3 | - | μs |

Notes:

7. Typical values are defined at TA = +25°C, VDD = 12V. Maximum and minimum values over the operating temperature range are not tested in production but guaranteed by design, process control and characterization.
8. VDD is the voltage between the VDD pin and the GND pin.
9. When power is initially turned on, V_{DD} must be operated in the correct voltage range to guarantee proper magnetic field sampling, output supply current state level is valid after the start up time of 28µs from V_{DD} higher than 2.7V. Guaranteed by design.
10. Time delayed from the magnetic threshold reached to the output rise or fall.

11. t > T_{PON} and $B_{RP} < B < B_{OP}$.



Magnetic Characteristics (Notes 12, 13) (T_A = -40°C to +150°C, T_J = -40°C to +165°C, V_{DD}= 2.7V to 27V, unless otherwise specified)

| Part Name | Test Condition | | rating Po _{DP} (Gauss | | | ease Poir - (Gauss) | | Temperature Coefficient (ppm/°C) | I _{OFF} (mA) | Active Pole | Output Polarity | |
|-----------|---------------------------|-----|-----------------------------------|-----|-----|------------------------|-----|--|--------------------------|----------------|--------------------|----------|
| | | Min | Тур | Max | Min | Тур | Max | Тур | Тур | | | |
| 41100440 | T _A =25°C | 65 | 90 | 120 | 45 | 70 | 100 | 0 | 0 | Courth | luo, contro d | |
| AH3241Q | T _A =-40~150°C | 55 | 90 | 135 | 35 | 70 | 115 | 0 | 6 | South | Inverted | |
| AH3242Q | T _A =25°C | 40 | 60 | 80 | 20 | 40 | 60 | 1100 | 6 | South | Direct | |
| AH3242Q | T _A =-40~150°C | 30 | 60 | 90 | 10 | 40 | 70 | -1100 | 0 | South | | |
| AH3243Q | T _A =25°C | 27 | 45 | 63 | 10 | 28 | 46 | -1100 | 6 | South | Direct | |
| AH3243Q | T _A =-40~150°C | 20 | 45 | 70 | 3 | 28 | 53 | | | South | | |
| AH3244Q | T _A =25°C | 27 | 45 | 63 | 10 | 28 | 46 | 1100 6 | -1100 | 6 | Couth | Inverted |
| AD3244Q | T _A =-40~150°C | 20 | 45 | 70 | 3 | 28 | 53 | -1100 | 0 | South | Inverted | |
| AH3280Q | T _A =25°C | 8 | 18 | 28 | -28 | -18 | -8 | | 0 3.3 | | South | Direct |
| AH3200Q | T _A =-40~150°C | 3 | 18 | 33 | -33 | -18 | -3 | 0 | 3.3 | South | Direct | |
| AU2204O | T _A =25°C | 8 | 18 | 28 | -28 | -18 | -8 | 0 | 6 | Couth | Direct | |
| AH3281Q | T _A =-40~150°C | 3 | 18 | 33 | -33 | -18 | -3 | | 6 | South | Direct | |
| AU22020 | T _A =25°C | 15 | 30 | 45 | -45 | -30 | -15 | | | Quarth | Direct | |
| AH3282Q | T _A =-40~150°C | 10 | 30 | 50 | -50 | -30 | -10 | 0 | 0 | 0 3.3 | .3 South | Direct |







- Notes: 12. Positive x-axis direction indicates the South Pole approaching the part marking surface of SIP3 and SC59 i.e. increasing south pole magnetic field strength to the sensor; reversing direction x-axis toward 0 means the decreasing south magnetic field strength to the sensor. Negative x-axis indicates north pole magnetic field to the part marking surface.
 - 13. Typical values are defined at $T_A = +25^{\circ}$ C, $V_{DD} = 12$ V. Maximum and minimum values over the operating temperature range is not tested in production but guaranteed by design, process control and characterization.



Typical Operating Characteristics



AH324XQ_AH328XQ Supply Current ON, Ion Performance

AH324XQ_AH3281Q Supply Current OFF, IOFF(1) Performance







Supply current off state versus Supply voltage

12 14 16 18 20 28

-TA= -40'C

- TA=+25'C

22 24 26

TA=+150'C



TA = -40'C

TA = +25'C

TA =+150'C

22 24 26 28

Typical Operating Characteristics (continued)



AH3241Q Magnetic Characteristics Performance



Release Point versus Temperature







Typical Operating Characteristics (continued)



AH3242Q Magnetic Characteristics Performance



50 Ambient Temperature, $T_A(^{\circ}C)$

75

100

125

150

-25

-50

0

25

Release Point versus Supply voltage



Switch Point Hysteresis versus Temperature Switch Point Hysteresis versus Supply voltage 40 40 Switch Point Hysteresis, B_{HY}(G) Switch Point Hysteresis, B_{HY}(G) AH3242Q AH3242Q VDD=2.7V -TA = -40'C 35 35 -TA = +25'C VDD=12V 30 30 -TA =+150'C VDD=27V 25 25 20 20 15 15 10 10 5 5 4 6 8 10 12 14 16 18 20 22 24 26 28 -50 -25 0 25 50 75 100 125 150 2 Supply Voltage, V_{DD} (V) Ambient Temperature, T_A(℃)



Typical Operating Characteristics (continued)



AH3243Q_AH3244Q Magnetic Characteristics Performance



Release Point versus Temperature 40 VDD=2.7V AH3243Q AH3244Q VDD=12V 35 VDD=27V Release Point, BRP(G) 30 25 20 15 10 -50 -25 0 25 50 75 100 125 150 Ambient Temperature, $T_A(^{\circ}C)$

Release Point versus Supply voltage







Typical Operating Characteristics (continued)



AH3280Q_AH3281Q Magnetic Characteristics Performance



Release Point versus Temperature -30 VDD=2.7V AH3280Q AH3281Q VDD=12V -25 VDD=27V Release Point, BRP(G) -20 -15 -10 -5 0 -50 -25 Ó 25 50 75 100 125 150 Ambient Temperature, T_A(℃)

Release Point versus Supply voltage



Switch Point Hysteresis versus Temperature 60 VDD=2.7V AH3280Q AH3281Q Switch Point Hysteresis, B_HY(G) 55 VDD=12V 50 VDD=27V 45 40 35 30 25 20 15 10 -50 -25 0 25 50 75 100 125 150 Ambient Temperature, T_A(℃)



Supply Voltage, V_{DD} (V)

Switch Point Hysteresis versus Supply voltage



-45

Typical Operating Characteristics (continued)



AH3282Q Magnetic Characteristics Performance



Release Point versus Temperature



-45 AH3282Q TA = -40'C -40 - TA = +25'C Release Point, B_{RP}(G) -35 -TA =+150'C -30 -25 -20 -15 -10 4 10 12 14 16 18 20 22 24 26 28 2 6 8 Supply Voltage, V_{DD} (V)

Release Point versus Supply voltage

Switch Point Hysteresis versus Temperature Switch Point Hysteresis versus Temperature 90 90 Switch Point Hysteresis, B_{HY}(G) Switch Point Hysteresis, B_{HY}(G) VDD=2.7V AH3282Q AH3282Q VDD=2.7V 80 80 VDD=12V VDD=12V VDD=27V VDD=27V 70 70 60 60 50 50 40 40 30 30 -50 -25 0 25 50 75 100 125 150 -50 -25 0 25 50 75 100 125 150 Ambient Temperature, T_A(°C) Ambient Temperature, T_A(°C)



Thermal Performance Characteristics

| Symbol | Parameter | Conditions | Rating | Unit |
|--|--|------------|--------|------|
| R $_{\theta JA}$ Package Thermal Resistance | SC59, 50mm*50mm 2oz MRB PCB, single layer | 268 | °C/W | |
| | SIP-3, 50mm*50mm 2oz MRB PCB, single layer | 143 | °C/W | |

Thermal Derating Curve vs. Ambient Temperature





Ordering Information



| | Deekers | | Bulk Box | | 7" Tape and Reel | | Amr | no Box |
|-------------|-----------------|----------------------|----------|-----------------------|------------------|-----------------------|----------|-----------------------|
| Part Number | Package Code | Packaging | Quantity | Part Number Suffix | Quantity | Part Number Suffix | Quantity | Part Number Suffix |
| AH3241Q-P-A | Р | SIP-3 (Ammo Pack) | NA | NA | NA | NA | 4000/Box | -A |
| AH3241Q-P-B | Р | SIP-3 (Bulk Pack) | 1000 | -В | NA | NA | NA | NA |
| AH3241Q-W-7 | W | SC59 (Type A1) | NA | NA | 3000/Tape & Reel | -7 | NA | NA |
| AH3242Q-P-A | Р | SIP-3 (Ammo Pack) | NA | NA | NA | NA | 4000/Box | -A |
| AH3242Q-P-B | Р | SIP-3 (Bulk Pack) | 1000 | -В | NA | NA | NA | NA |
| AH3242Q-W-7 | W | SC59 (Type A1) | NA | NA | 3000/Tape & Reel | -7 | NA | NA |
| AH3243Q-P-A | Р | SIP-3 (Ammo Pack) | NA | NA | NA | NA | 4000/Box | -A |
| AH3243Q-P-B | Р | SIP-3 (Bulk Pack) | 1000 | -В | NA | NA | NA | NA |
| AH3243Q-W-7 | W | SC59 (Type A1) | NA | NA | 3000/Tape & Reel | -7 | NA | NA |
| AH3244Q-P-A | Р | SIP-3 (Ammo Pack) | NA | NA | NA | NA | 4000/Box | -A |
| AH3244Q-P-B | Р | SIP-3 (Bulk Pack) | 1000 | -В | NA | NA | NA | NA |
| AH3244Q-W-7 | W | SC59 (Type A1) | NA | NA | 3000/Tape & Reel | -7 | NA | NA |
| AH3280Q-P-A | Р | SIP-3 (Ammo Pack) | NA | NA | NA | NA | 4000/Box | -A |
| AH3280Q-P-B | Р | SIP-3 (Bulk Pack) | 1000 | -В | NA | NA | NA | NA |
| AH3280Q-W-7 | W | SC59 (Type A1) | NA | NA | 3000/Tape & Reel | -7 | NA | NA |
| AH3281Q-P-A | Р | SIP-3 (Ammo Pack) | NA | NA | NA | NA | 4000/Box | -A |
| AH3281Q-P-B | Р | SIP-3 (Bulk Pack) | 1000 | -В | NA | NA | NA | NA |
| AH3281Q-W-7 | W | SC59 (Type A1) | NA | NA | 3000/Tape & Reel | -7 | NA | NA |
| AH3282Q-P-A | Р | SIP-3 (Ammo Pack) | NA | NA | NA | NA | 4000/Box | -A |
| AH3282Q-P-B | Р | SIP-3 (Bulk Pack) | 1000 | -В | NA | NA | NA | NA |
| AH3282Q-W-7 | W | SC59 (Type A1) | NA | NA | 3000/Tape & Reel | -7 | NA | NA |

 Ammo Box is for SIP-3 (Ammo Pack) Spread Lead.
 Bulk is for SIP-3 (Bulk Pack) Straight Lead. Notes:



Marking Information

(1) Package Type: SC59 (Type-A1)



| Part Number | Package | Identification Code |
|-------------|----------------|---------------------|
| AH3241Q | SC59 (Type A1) | BR |
| AH3242Q | SC59 (Type A1) | BS |
| AH3243Q | SC59 (Type A1) | BT |
| AH3244Q | SC59 (Type A1) | BX |
| AH3280Q | SC59 (Type A1) | BW |
| AH3281Q | SC59 (Type A1) | BU |
| AH3282Q | SC59 (Type A1) | BV |

(2) Package Type: SIP-3 (Ammo Pack), SIP-3 (Bulk Pack)





Package Outline Dimensions (All dimensions in mm.)

Please see http://www.diodes.com/package-outlines.html for the latest version.

(1) Package Type: SC59 (Type A1)





| 6 | | | | |
|-----|----------|--------|-------|--|
| | SC59 (| Туре / | A1) | |
| Dim | Min | | | |
| Α | | 1.45 | | |
| A1 | 0.00 | 0.15 | | |
| A2 | 0.90 | 1.30 | 1.15 | |
| b | 0.30 | 0.50 | - | |
| С | 0.08 | 0.22 | | |
| D | 2.90 BSC | | | |
| E | | 2.80 B | SC | |
| E1 | | 1.60 B | SC | |
| е | | 0.95 B | SC | |
| e1 | | 1.90 B | SC | |
| L | 0.30 | 0.60 | 0.45 | |
| L2 | 0.25 BSC | | | |
| θ1 | 5° | 15° | 10° | |
| All | Dimen | sions | in mm | |

AH32xxQ Hall sensor





Package Outline Dimensions (continued) (All dimensions in mm.)

Please see http://www.diodes.com/package-outlines.html for the latest version.

(2) Package Type: SIP-3 (Bulk Pack)



| S | IP-3 (Bu | Ik Pack | () | |
|-------|-------------|----------------|-------|--|
| Dim | Min | Max | Тур | |
| Α | 1.40 | 1.60 | 1.50 | |
| b | 0.33 | 0.43 | 0.38 | |
| b2 | 0.40 | 0.508 | 0.46 | |
| С | 0.35 | 0.41 | 0.38 | |
| D | 3.90 | 4.30 | 4.10 | |
| E | 2.80 | 2.80 3.20 3.00 | | |
| e1 | 1.24 | 1.30 | 1.27 | |
| F | 0.00 0.20 — | | | |
| J | 2 | .62 REF | - | |
| L | 14.00 | 15.00 | 14.50 | |
| L1 | 1.55 | 1.75 | 1.65 | |
| S | 0.63 | 0.84 | 0.74 | |
| a1 | | - | 5° | |
| a2 | | | 5° | |
| a3 | _ | _ | 45° | |
| a4 | _ | _ | 3° | |
| All C | Dimensi | ons in | mm | |

AH32xxQ SIP3 Hall sensor





Package Outline Dimensions (continued) (All dimensions in mm.)

Please see http://www.diodes.com/package-outlines.html for the latest version.

(3) Package Type: SIP-3 (Ammo Pack)



| | SIF | 0_3 | | | |
|-------|---------------|-------------|-------|--|--|
| | (Ammo | - | | | |
| Dim | Min | Max | Тур | | |
| Α | 1.40 | 1.60 | 1.50 | | |
| b | 0.33 | 0.43 | 0.38 | | |
| b2a | 0.40 | 0.52 | 0.46 | | |
| c | 0.35 | 0.41 | 0.38 | | |
| D | 3.90 | 4.30 | 4.10 | | |
| ш | 2.80 | 3.20 | 3.00 | | |
| e1 | 1.24 1.30 1.2 | | | | |
| e2 | 2.40 | 2.90 | 2.65 | | |
| F | 0.00 | 0.00 0.20 — | | | |
| J | 2 | .62 REF | - | | |
| L | 14.00 | 15.00 | 14.50 | | |
| La | 12.90 | 14.90 | 13.90 | | |
| L1 | 1.55 | 1.75 | 1.65 | | |
| L3 | 2.00 | 3.00 | 2.50 | | |
| S | 0.63 | 0.84 | 0.74 | | |
| a1 | | _ | 5° | | |
| a2 | | _ | 5° | | |
| a3 | | _ | 45° | | |
| a4 | | _ | 3° | | |
| All [| Dimensi | ons in | mm | | |

AH32xxQ SIP3 Hall sensor



AH3241Q-AH3244Q/AH3280Q-AH3282Q Document number: DS41822 Rev. 5 - 2



Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

(1) Package Type: SC59 (Type A1)



| Dimensions | Value (in mm) |
|------------|---------------|
| С | 2.40 |
| Х | 0.80 |
| X1 | 1.35 |
| Y | 1.00 |
| Y1 | 3.40 |



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